L Number	Hits	Search Text	DB	Time stamp
1	377	((ge germanium) near2 (Si silicon)) near12 interface	USPAT;	2004/02/12 19:46
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
2	16	(((ge germanium) near2 (Si silicon)) near12 interface) near12	USPAT;	2004/02/12 19:53
		(nanometer nm ang angstoms \$3ang.\$1 micron micrometer	US-PGPUB;	
		\$3mu.m)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	-
3	1030	((ge germanium) near2 (Si silicon)) near12 (nanometer nm	USPAT;	2004/02/12 19:54
		ang angstoms \$3ang.\$1 micron micrometer \$3mu.m)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	_		IBM_TDB	0004/00/40 40:50
4	0	(((ge germanium) near2 (Si silicon)) near12 (nanometer nm	USPAT;	2004/02/12 19:53
		ang angstoms \$3ang.\$1 micron micrometer \$3mu.m)) and	US-PGPUB;	
		sililcide .	EPO; JPO;	
			DERWENT;	
_	224		IBM_TDB	2004/02/42 20:02
5	201	(((ge germanium) near2 (Si silicon)) near12 (nanometer nm	USPAT;	2004/02/12 20:02
		ang angstoms \$3ang.\$1 micron micrometer \$3mu.m)) and	US-PGPUB;	
		(salicide silicide)	EPO; JPO;	
			DERWENT;	
	24	///na marmanium) nagr? (Si pilipan)) nagr!? (nanamatar nm	IBM_TDB USPAT;	2004/02/12 19:53
6	21	((((ge germanium) near2 (Si silicon)) near12 (nanometer nm	US-PGPUB;	2004/02/12 19.55
		ang angstoms \$3ang.\$1 micron micrometer \$3mu.m)) same (salicide silicide)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
7	380	((ge germanium) near2 (Si silicon)) near12 (silicide salicide)	USPAT;	2004/02/12 19:54
'	300	((ge germanium) flear2 (or silicon)) flear 12 (silicide salicide)	US-PGPUB;	200-1/02/12 10:04
			EPO; JPO;	
			DERWENT;	,
			IBM_TDB	
8	46	(((ge germanium) near2 (Si silicon)) near12 (nanometer nm	USPAT;	2004/02/12 19:54
		ang angstoms \$3ang.\$1 micron micrometer \$3mu.m)) and	US-PGPUB	
		(((ge germanium) near2 (Si silicon)) near12 (silicide salicide))	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
9	23	((((ge germanium) near2 (Si silicon)) near12 (nanometer nm	USPAT;	2004/02/12 20:02
		ang angstoms \$3ang.\$1 micron micrometer \$3mu.m)) and	US-PGPUB;	
		(((ge germanium) near2 (Si silicon)) near12 (silicide	EPO; JPO;	
		salicide))) and @ad <20000306	DERWENT;	
			IBM_TDB	
10	13	((((ge germanium) near2 (Si silicon)) near12 (nanometer nm	USPAT;	2004/02/12 19:54
		ang angstoms \$3ang.\$1 micron micrometer \$3mu.m)) and	US-PGPUB;	
		(((ge germanium) near2 (Si silicon)) near12 (silicide	EPO; JPO;	
	•	salicide))) and @rlad <20000306	DERWENT;	
<u></u>			IBM_TDB	0004/00/40 00:01
11	28	(((((ge germanium) near2 (Si silicon)) near12 (nanometer nm	USPAT;	2004/02/12 20:01
		ang angstoms \$3ang.\$1 micron micrometer \$3mu.m)) and	US-PGPUB;	
		(((ge germanium) near2 (Si silicon)) near12 (silicide	EPO; JPO;	
		salicide))) and @ad <20000306) (((((ge germanium) near2	DERWENT;	
		(Si silicon)) near12 (nanometer nm ang angstoms \$3ang.\$1	IBM_TDB	ļ
		micron micrometer \$3mu.m)) and (((ge germanium) near2		
40		(Si silicon)) near12 (silicide salicide))) and @rlad <20000306)	LICEAT	2004/02/42 22:02
12	206	(Ge germanium) near3 (migrat\$3 diffus\$4 mov\$3) near12	USPAT;	2004/02/12 20:02
		(surface interface face)	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM_TDB	
			TIDINITIDE	

13	35	((Ge germanium) near3 (migrat\$3 diffus\$4 mov\$3) near12	USPAT;	2004/02/12 20:02
13	35	((Ge germanium) heard (migrated unidset moves) hear iz	US-PGPUB:	2004/02/12 20.02
		(Surface interface face)) and (Sanciae Sinciae)	EPO; JPO;	
			DERWENT:	
			IBM TDB	
14	21	(((Ge germanium) near3 (migrat\$3 diffus\$4 mov\$3) near12	USPAT:	2004/02/12 20:02
' '		(surface interface face)) and (salicide silicide)) and @ad	US-PGPUB:	
		<20000306	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
15	10	(((Ge germanium) near3 (migrat\$3 diffus\$4 mov\$3) near12	USPAT;	2004/02/12 20:02
		(surface interface face)) and (salicide silicide)) and @rlad	US-PGPUB;	
		<20000306	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
16	23	((((Ge germanium) near3 (migrat\$3 diffus\$4 mov\$3) near12	USPAT;	2004/02/12 20:22
		(surface interface face)) and (salicide silicide)) and @ad	US-PGPUB;	
		<20000306) ((((Ge germanium) near3 (migrat\$3 diffus\$4	EPO; JPO;	
		mov\$3) near12 (surface interface face)) and (salicide	DERWENT;	
40	000	silicide)) and @rlad <20000306)	IBM_TDB USPAT:	2004/02/12 20:24
18	890	(cabral carruthers harper lavoie roy wang).in. and (international adj business adj machines).asn.	US-PGPUB:	2004/02/12 20.24
	1	(International adj business adj machines).asn.	EPO; JPO;	
			DERWENT;	
			IBM TDB	
19	3	(((ge germanium) near2 (Si silicon)) near12 interface) and	USPAT;	2004/02/12 20:24
'		((cabral carruthers harper lavoie roy wang).in. and	US-PGPUB;	
		(international adj business adj machines).asn.)	EPO; JPO;	
		\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	DERWENT;	
			IBM_TDB	